## NSN 5961-01-024-1010

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View Online at https://aerobasegroup.com/nsn/5961-01-024-1010

## Inclosure Material:

Metal

**Overall Length:** 

1.252 inches

## **Overall Height:**

0.340 inches

## **Overall Width:**

0.700 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

#### Unthreaded hole

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,

static, collector open

#### **Current Rating Per Characteristic:**

Between 500.00 milliamperes source cutoff current and 2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

20.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Precious Material And Location:**

Terminal surface option gold

#### **Precious Material:**

Gold

#### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

81349-mil-s-19500/454 government specification

#### Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

